



**DYNAMIC CHARACTERISTICS**

	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		11715	14000	pF
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		1430	2000	
$C_{rss}$	Reverse Transfer Capacitance	$f = 1MHz$		460	690	
$Q_g$	Total Gate Charge <sup>3</sup>	$V_{GS} = 10V$		468	700	nC
$Q_{gs}$	Gate – Source Charge	$V_{DD} = 0.5 V_{DSS}$		72	110	
$Q_{gd}$	Gate – Drain (“Miller”) Charge	$I_D = I_D [Cont.] @ 25^\circ C$		176	265	
$t_{d(on)}$	Turn-on Delay Time	$V_{GS} = 15V$		21	40	ns
$t_r$	Rise Time	$V_{DD} = 0.5 V_{DSS}$		19	40	
$t_{d(off)}$	Turn-off Delay Time	$I_D = I_D [Cont.] @ 25^\circ C$		70	105	
$t_f$	Fall Time	$R_G = 0.6\Omega$		13	25	

**SOURCE – DRAIN DIODE RATINGS AND CHARACTERISTICS**

	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
$I_S$	Continuous Source Current (Body Diode)				40	A
$I_{SM}$	Pulsed Source Current <sup>1</sup> (Body Diode)				160	
$V_{SD}$	Diode Forward Voltage <sup>2</sup>	$V_{GS} = 0V, I_S = -I_D [Cont.]$			1.8	V
$t_{rr}$	Reverse Recovery Time	$I_S = -I_D [Cont.]$	470	945	1800	ns
$Q_{rr}$	Reverse Recovery Charge	$di_S / dt = 100A/\mu s$	18	36	60	$\mu C$

**PACKAGE CHARACTERISTICS**

	Characteristic	Min.	Typ.	Max.	Unit
$L_D$	Internal Drain Inductance (Measured From Drain Terminal to Centre of Die)		3		nH
$L_S$	Internal Source Inductance (Measured From Source Terminals to Source Bond Pads)		5		
$V_{isolation}$	RMS Voltage (50–60 Hz Sinusoidal Waveform From Terminals to Mounting Base for 1 Min.)	2500			V
$C_{isolation}$	Drain-to-Mounting Base Capacitance		70		pF
Torque	Maximum Torque for Device Mounting Screws and Electrical Terminations			13	in-lbs

**THERMAL CHARACTERISTICS**

	Characteristic	Min.	Typ.	Max.	Unit
$R_{\theta JC}$	Junction to Case			0.18	$^\circ C/W$
$R_{\theta CS}$	Case to Sink (Use High Efficiency Thermal Joint Compound and Planar Heat Sink Surface.)		0.05		

1) Repetitive Rating: Pulse Width limited by maximum junction temperature.

2) Pulse Test: Pulse Width < 380 $\mu s$ , Duty Cycle < 2%

3) See MIL–STD–750 Method 3471



CAUTION — Electrostatic Sensitive Devices. Anti-Static Procedures Must Be Followed.